

Search History (16 pp) ~~16~~ (06/18/05)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	("baseadjfilmnear6oxynitride").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 19:22
L2	237	base adj film near6 oxynitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 19:22
L3	10	base adj film near6 oxynitride near6 hydrogenated	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 19:27
L4	11	base adj (layer film) near15 oxynitride near15 hydrogenat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 19:28
L5	13	base adj (layer film) near15 oxynitride near15 hydrogen\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 19:41
L6	5480	((257/52) or (257/57) or (257/59) or (257/66) or (257/72) or (257/346) or (257/365)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 19:42
L7	110	L6 and oxynitride and (hydrogen hydrogenat\$3) and nitrogen near10 (density concentration abundance) and (buffer base) and (field adj effect adj transistor tft thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/18 19:45
L8	187747	L6 and oxynitride and (hydrogen hydrogenat\$3) and nitrogen near10 (density concentration abundance) near10 (base buffer) (field adj effect adj transistor tft thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/18 19:46
L9	1	L6 and oxynitride and (hydrogen hydrogenat\$3) and nitrogen near10 (density concentration abundance) near10 (base buffer) and (field adj effect adj transistor tft thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/18 19:46

S1	3	"669284".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 14:50
S2	377	(257/365).CCLS.	US-PGPUB; USPAT	OR	OFF	2004/12/28 16:33
S3	18	S2 and oxynitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/28 16:39
S4	1	S2 and oxynitride and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/28 16:40
S5	853	(tft thin adj film adj transistor) and oxynitride and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/28 16:40
S6	81	(tft thin adj film adj transistor) and hydrogenated near4 oxynitride and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/28 16:41
S7	81	(tft thin adj film adj transistor) and hydrogenated near3 oxynitride and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 16:49
S8	81	(tft thin adj film adj transistor) and (gate near3 insulat\$3 oxide) and hydrogenated near3 oxynitride and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 16:53
S9	2	(tft thin adj film adj transistor) and (gate near3 insulat\$3 oxide) near8 hydrogenated near3 oxynitride and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 16:51
S10	1	(tft thin adj film adj transistor) and (gate near3 (insulat\$3 oxide)) near8 hydrogenated near3 oxynitride and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 16:51

S11	2	jp-08055847\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 17:21
S12	0	driver adj (region area section portion) and pixel adj (region area section portion) and (tft thin adj film adj transistor) and oxynitride near6 hydrogenated near6 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 17:24
S13	10	driver adj (region area section portion) and pixel adj (region area section portion) and (tft thin adj film adj transistor) and oxynitride near6 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 17:24
S14	6	driver adj (region area section portion) and pixel adj (region area section portion) and (tft thin adj film adj transistor) and oxynitride near6 gate and hydrogenated	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 17:24
S15	4	driver adj (region area section portion) and pixel adj (region area section portion) and (tft thin adj film adj transistor) and oxynitride near6 gate and hydrogenated and (lightly adj doped adj drain ldd)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 17:26
S16	4	driver adj (region area section portion) and pixel adj (region area section portion) and (tft thin adj film adj transistor) and (SiON oxynitride) near6 gate and hydrogenated and (lightly adj doped adj drain ldd)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 17:29
S17	85	driver adj (region area section portion) and pixel adj (region area section portion) and (tft thin adj film adj transistor) and (lightly adj doped adj drain ldd)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/28 17:34
S18	1	("6834818").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/28 17:35
S19	2	("6384818").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/28 17:37

S20	2	JP-10104663\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/28 17:37
S21	8	(US-20040007748-\$ or US-20040238820-\$).did. or (US-6064091-\$ or US-6384818-\$ or US-6740938-\$).did. or (JP-08055847-\$).did. or (JP-08055847-\$ or JP-10104663-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 11:01
S22	2	jp-08277486\$-\$.did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 10:51
S23	2	("6384818").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:10
S24	4	("5970384").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:10
S25	0	S24 and pixel near3 circuit and driver near3 circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:11
S26	0	S24 and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:11
S27	0	S24 and pixel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:11
S28	0	S24 and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:21
S29	130	hydrogenated near4 (oxynitride "SiO:N" "Si:ON")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:22

S30	0	hydrogenated near4 ("SiO:N" "Si:ON")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:22
S31	61	hydrogenated near4 oxynitride and (ldd lightly adj doped adj drain) and (tft thin adj film adj transistor) and pixel and driver and (overlap overlapped overlapping)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:24
S33	56	hydrogenated near4 oxynitride and (ldd lightly adj doped adj drain) and (tft thin adj film adj transistor) and pixel near2 (region area portion) and driver near2 (region area portion) and (overlap overlapped overlapping)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:25
S34	55	hydrogenated near4 oxynitride and (ldd lightly adj doped adj drain) and (tft thin adj film adj transistor) and pixel near2 (region area portion) and driver near2 (region area portion) and (overlap overlapped overlapping) near6 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:25
S35	20	hydrogenated near4 oxynitride and (ldd lightly adj doped adj drain) and (tft thin adj film adj transistor) and pixel near2 (region area portion) and driver near2 (region area portion) and (overlap overlapped overlapping) near6 gate and third near3 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:29
S36	55	hydrogenated near4 oxynitride and (ldd lightly adj doped adj drain) and (tft thin adj film adj transistor) and pixel near2 (region area portion) and driver near2 (region area portion) and (overlap overlapped overlapping) near6 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:29
S37	35	hydrogenated near4 oxynitride and (ldd lightly adj doped adj drain) and (tft thin adj film adj transistor) and pixel near2 (region area portion) and driver near2 (region area portion) and (overlap overlapped overlapping) near6 gate and (S36 not S35)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:35

S38	438	overlap near3 gate near4 (advantage reduce increase)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:35
S39	55	overlap near3 gate near4 (advantage reduce increase) and tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:35
S40	9	overlap near3 gate near4 (advantage reduce increase) and (thin adj film adj transistor tft).ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:40
S41	3	overlap near3 gate near4 (advantage reduce increase) and (thin adj film adj transistor tft).ti. and pixel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:45
S42	259	overlap near3 gate and (thin adj film adj transistor tft).ti. and pixel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:45
S43	75	overlap near3 gate.ti,ab,clm. and (thin adj film adj transistor tft).ti. and pixel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:45
S44	15	overlap near3 gate.ti,ab,clm. and (thin adj film adj transistor tft).ti. and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:46
S45	1	overlap near3 gate.ti,ab,clm. and (thin adj film adj transistor tft).ti. and pixel and driver and oxynitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 11:46
S46	2	("5804878").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 13:44
S49	0	("hydrogenatednear3oxynitridene r10gateinsulat\$3andthinadjfilmadj ransistor.ti,ab,clm.").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 15:45

S50	0	hydrogenated near3 oxynitride near10 gate adj insulat\$3 and thin adj film adj transistor.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 15:46
S51	1	hydrogenated near3 oxynitride near10 gate adj insulat\$3 and thin adj film adj transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 15:47
S52	2	SiON near3 hydrogenated	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 15:49
S53	25	SiON near3 hydrogenated SiON:H	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 15:51
S54	0	(SiON near3 hydrogenated SiON:H) near20 gate adj (insulation insulating) and thin adj film adj transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 15:50
S55	0	(SiON near3 hydrogenated SiON:H) near20 gate and thin adj film adj transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 15:50
S56	0	SiON:H near10 gate adj (insulating insulation)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:07
S57	1930	video and personal adj computer and video adj camera and projector	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:08
S58	475	video and personal adj computer and video adj camera and projector and (thin adj film adj transistor).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:08
S59	391	video and personal adj computer and video adj camera and projector and (thin adj film adj transistor).ti,ab,clm. and gate adj (insulation insulating) adj film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:08



S60	187	(video and personal adj computer and video adj camera and projector).ti,ab,clm. and (thin adj film adj transistor).ti,ab,clm. and gate adj (insulation insulating) adj film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:09
S61	147	(video and personal adj computer and video adj camera and projector).ti,ab,clm. and (thin adj film adj transistor).ti,ab,clm. and gate adj (insulation insulating) adj film and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:09
S62	0	(video and personal adj computer and video adj camera and projector).ti,ab,clm. and (thin adj film adj transistor).ti,ab,clm. and gate adj (insulation insulating) adj film and pixel adj portion and driver adj portion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:09
S63	0	(video and personal adj computer and video adj camera and projector).ti,ab,clm. and (thin adj film adj transistor).ti,ab,clm. and gate adj (insulation insulating) adj film and pixel and driver adj portion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:10
S64	147	(video and personal adj computer and video adj camera and projector).ti,ab,clm. and (thin adj film adj transistor).ti,ab,clm. and gate adj (insulation insulating) adj film and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:10
S65	78	(video and personal adj computer and video adj camera and projector).ti,ab,clm. and (thin adj film adj transistor).ti,ab,clm. and gate adj (insulation insulating) adj film.ti,ab,clm. and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:12
S66	153	(video and personal adj computer and video adj camera and projector).ti,ab,clm. and (thin adj film adj transistor).ti,ab,clm. and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/29 17:12
S67	12	(US-20040007748-\$ or US-20040238820-\$).did. or (US-6064091-\$ or US-6384818-\$ or US-6740938-\$ or US-5970384-\$ or US-6673659-\$ or US-5804878-\$).did. or (JP-08055847-\$).did. or (JP-08055847-\$ or JP-10104663-\$ or US-20040169183-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 17:15



S68	211	driver and pixel and tft and video and portable and digital and disk and game and projector	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 17:18
S69	3576	driver and pixel and tft and video	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 17:18
S70	738	driver and pixel and tft and video and portable and game	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 17:20
S71	2	jp-10101974\$-\$\$.did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 17:20
S72	1	jp-11101974\$-\$\$.did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 17:31
S73	1177	(electrolumiscence EL) adj (display device) and thin adj film adj transistor.ti,ab,clm.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 17:32
S74	438	(electrolumiscence EL) adj (display device) and thin adj film adj transistor.ti,ab,clm. and pixel and driver	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/29 17:33
S75	2	(electrolumiscence EL) adj (display device) and thin adj film adj transistor.ti,ab,clm. and pixel and driver	JPO	OR	OFF	2004/12/29 17:34
S76	1425	(EL adj display electroluminescence adj display) and (thin adj film adj transistor tft) and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 07:18
S77	292	(EL adj display electroluminescence adj display). ti,ab,clm. and (thin adj film adj transistor tft).ti,ab,clm. and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 07:18
S78	139	(EL adj display electroluminescence adj display). ti,ab,clm. and (thin adj film adj transistor tft).ti,ab,clm. and pixel near3 tft and driver near3 tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 07:23

S79	0	("669284.ap.").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 07:22
S80	3	"669284".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 07:22
S81	292	(EL adj display electroluminescence adj display).ti,ab,clm. and (thin adj film adj transistor tft).ti,ab,clm. and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 07:23
S82	153	((EL adj display electroluminescence adj display).ti,ab,clm. and (thin adj film adj transistor tft).ti,ab,clm. and pixel and driver) not S78	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 09:02
S83	1	"5804878".pn. and source and channel and drain	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 09:40
S84	123	organic adj resin near8 interlayer adj (dielectric insulat\$3) adj (film layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 09:41
S85	75	organic adj resin near8 interlayer adj (dielectric insulat\$3) adj (film layer) and (thin adj film adj transistor tft).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 09:42
S86	9	organic adj resin near8 interlayer adj (dielectric insulat\$3) adj (film layer).ti,ab,clm. and (thin adj film adj transistor tft).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 09:44
S87	7	organic adj resin near8 interlayer adj (dielectric insulat\$3) adj (film layer).ti,ab,clm. and (thin adj film adj transistor tft).ti,ab,clm. and pixel adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 09:45
S88	2	"5784073".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 09:47

S89	1	"5784073".pn. and organic adj resin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 10:28
S90	1	"5784073".pn. and organic adj resin and flatten\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 11:09
S91	2068	((257/365) or (257/346) or (257/365) or (257/72)).CCLS.	US-PGPUB; USPAT	OR	OFF	2004/12/30 11:29
S92	513	S91 and gate and pixel and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 13:43
S93	11	((("5,323,042") or ("5,970,384") or ("6,166,414") or ("6,198,133") or ("6,281,552") or ("6,306,694") or ("6,399,988") or ("6,429,483") or ("6,524,895") or ("6,531,713") or ("6,534,826"))).PN.	USPAT	OR	OFF	2004/12/30 13:44
S94	9	((("5,247,190") or ("5,399,507") or ("5,504,020") or ("5,640,067") or ("5,643,826") or ("5,897,328") or ("5,923,962") or ("5,970,384") or ("6,461,899"))).PN.	USPAT	OR	OFF	2004/12/30 13:48
S95	9	(US-6461899-\$ or US-5970384-\$ or US-5923962-\$ or US-5897328-\$ or US-5643826-\$ or US-5640067-\$ or US-5504020-\$ or US-5399507-\$ or US-5247190-\$).did.	USPAT	OR	OFF	2004/12/30 13:49
S96	2	jp-04369271\$-\$ did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 13:52
S97	2	jp-05102483\$-\$ did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 13:53
S98	2	jp-07335900\$-\$ did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 13:54

S99	2	jp-08078329\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 13:55
S10 0	2	jp-10135468\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 13:55
S10 1	2	jp-10135469\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:11
S10 2	0	wo-9013148\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:11
S10 3	0	wo-90013148\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:11
S10 4	0	wo-1990013148\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:11
S10 5	0	wo-1990013148\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:11
S10 6	0	wo-90013148\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:11
S10 7	1	wo-9013148\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:13
S10 8	1	jp-07130652\$-\$\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:14

S10 9	2	jp-08055846\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:21
S11 0	2	jp-08055847\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:22
S11 1	2	jp-08055848\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:23
S11 2	2	jp-10092576\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:25
S11 3	2	jp-10247735\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/30 14:25

S11 4	57	(US-20040007748-\$ or US-20040238820-\$).did. or (US-5804878-\$ or US-5970384-\$ or US-6064091-\$ or US-6384818-\$ or US-6673659-\$ or US-6740938-\$ or US-5684365-\$ or US-5784073-\$ or US-6777763-\$ or US-6747289-\$ or US-6448612-\$ or US-6441399-\$ or US-6259120-\$ or US-6160269-\$ or US-5818070-\$ or US-5789762-\$ or US-5712495-\$ or US-5677549-\$ or US-5619045-\$ or US-5572046-\$ or US-6534826-\$ or US-6531713-\$ or US-6524895-\$ or US-6429483-\$ or US-6399988-\$ or US-6306694-\$).did. or (US-6281552-\$ or US-6198133-\$ or US-6166414-\$ or US-5323042-\$ or US-6461899-\$ or US-5923962-\$ or US-5897328-\$ or US-5643826-\$ or US-5640067-\$ or US-5504020-\$ or US-5399507-\$ or US-5247190-\$).did. or (JP-08055847-\$ or JP-04369271-\$ or JP-05102483-\$ or JP-07335900-\$ or JP-08078329-\$ or JP-10135468-\$ or JP-10135469-\$ or JP-08055846-\$ or JP-08055848-\$ or JP-10092576-\$ or JP-10247735-\$).did. or (JP-08055847-\$ or JP-10104663-\$ or JP-11101974-\$ or US-20040169183-\$ or EP-423283-\$ or EP-651431-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/30 15:02
----------	----	--	--	----	-----	------------------

S11 5	57	(US-20040007748-\$ or US-20040238820-\$).did. or (US-5804878-\$ or US-5970384-\$ or US-6064091-\$ or US-6384818-\$ or US-6673659-\$ or US-6740938-\$ or US-5684365-\$ or US-5784073-\$ or US-6777763-\$ or US-6747289-\$ or US-6448612-\$ or US-6441399-\$ or US-6259120-\$ or US-6160269-\$ or US-5818070-\$ or US-5789762-\$ or US-5712495-\$ or US-5677549-\$ or US-5619045-\$ or US-5572046-\$ or US-6534826-\$ or US-6531713-\$ or US-6524895-\$ or US-6429483-\$ or US-6399988-\$ or US-6306694-\$).did. or (US-6281552-\$ or US-6198133-\$ or US-6166414-\$ or US-5323042-\$ or US-6461899-\$ or US-5923962-\$ or US-5897328-\$ or US-5643826-\$ or US-5640067-\$ or US-5504020-\$ or US-5399507-\$ or US-5247190-\$).did. or (JP-08055847-\$ or JP-04369271-\$ or JP-05102483-\$ or JP-07335900-\$ or JP-08078329-\$ or JP-10135468-\$ or JP-10135469-\$ or JP-08055846-\$ or JP-08055848-\$ or JP-10092576-\$ or JP-10247735-\$).did. or (JP-08055847-\$ or JP-10104663-\$ or JP-11101974-\$ or US-20040169183-\$ or EP-423283-\$ or EP-651431-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2004/12/30 15:02
S11 6	25	"5970384"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/20 06:19
S11 7	4	("5970384").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/20 06:19
S11 8	0	("669284.ap.").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 14:50



S11 9	3	"669284".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 15:10
S12 0	4	("5970384").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 16:25
S12 1	0	("teos(").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 16:25
S12 2	0	("teos.ti.").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 16:26
S12 3	0	"teos ("	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 16:26
S12 4	2899	teos.ti.ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 16:26
S12 5	288	teos.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 16:26
S12 6	288	teos.ti. and "(teos)"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 17:20
S12 7	2	("5804878").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/18 19:22